

ISIT2011 ISIT 2011

#1569420765: On Codes that Correct Asymmetric Errors with Graded Magnitude Distribution

Property	Change Add	Value							
Conference and <i>track</i>		2011 IEEE International Symposium on Information Theory - 2011 IEEE International Symposium on Information Theory							
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Presenter		presenter not specified							
Registration									
Category		Eligible for ISIT Student Paper Award							
Title		On Codes that Correct Asymmetric Errors with Graded Magnitude Distribution							
Abstract		In multi-level flash memories, the dominant cell errors are asymmetric with limited-magnitude. With such an error model in mind, Cassuto et al. recently developed bounds and constructions for codes correcting \$\$\$ asymmetric errors with magnitude no more than \$\ell\$. However, a more refined model of these memory devices reflects the fact that typically only a small number of errors have large magnitude while the remainder are of smaller magnitude. In this work, we study such an error model, in which at most \$ t_1 \$ errors of maximum magnitude \$ e_1^{s} , with \$ e_1^{s} , and at most \$ t_2 \$ errors of maximum magnitude \$ e_1^{s} , with \$ e_1^{s} , and code construction of Cassuto, et al. for the refined error model and assess the relative efficiency of the new codes. We then consider in more detail specific constructions for the case where \$ $t_1=t_2=1$ \$, \$ $e_1=1$ \$, and \$ $e_2>1$ \$.							
Topics		Coding theory and practice							
Session DOI		The program is not yet visible (tpc)							
Status	×	accepted							
Review manuscript		Document (show)	Pages	File size	Changed	IVII	D5 S	milarity score	
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Final manuscript	⊅	Can upload 5 pages until May 31, 2011 00:00:00 EDT.							
Personal notes									
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Reviews									

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1 Review

Review 1 (Reviewer C)

Importance

Very Important (4) Good technical level (4) Average Novelty (3) Good (4) Recommend (4)

Strengths (What are the key strengths of this paper?)

The paper is strong in two aspects: (1) It explores a new and interesting topic for multi-level flash memories -- namely, the design of ECC where large errors are less likely to appear than small errors, -- which is practically very important. (2) It presents new code constructions for the general error model considered in the paper (namely, asymmetric errors with graded magnitude distribution), and shows more efficient code constructions when the number and size of errors are much more restricted.

The paper is well written.

Weaknesses (What are the major weaknesses of this paper?)

No major weakness I can think of.

Comments and Recommendation (Please give the reasoning for your overall recommendation and any additional comments you wish to add.)

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The paper is well written.

1 Summary review by TPC member

Review 1 (Reviewer A)

TPC recommendation

Strong accept (5)

TPC Recommendation Justification (Please give a justification for your recommendation, especially if the review scores vary widely or your recommendation differs significantly from those of the reviewers.)

Correction of asymmetric errors with limited magnitude is very important in flash memories. This paper present error-correcting codes in this direction. A must accept.



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